



The Abdus Salam
International Centre for Theoretical Physics



2162-5

**Advanced Workshop on Anderson Localization, Nonlinearity and
Turbulence: a Cross-Fertilization**

23 August - 3 September, 2010

**INTRODUCTORY
Anderson Localization - Introduction**

Boris ALTSHULER
*Columbia University, Dept. of Physics, New York
NY
U.S.A.*

Anderson localization - introduction

Boris Altshuler

Physics Department, Columbia University



**Advanced Workshop on Anderson Localization,
Nonlinearity and Turbulence: a Cross-Fertilization
August 23 – September 03, 2010**



The Abdus Salam
International Centre for Theoretical Physics



IAEA
International Atomic Energy Agency

One-particle Localization

>50 years of Anderson Localization

PHYSICAL REVIEW

VOLUME 109, NUMBER 3

MARCH 1, 1958

Absence of Diffusion in Certain Random Lattices

P. W. ANDERSON

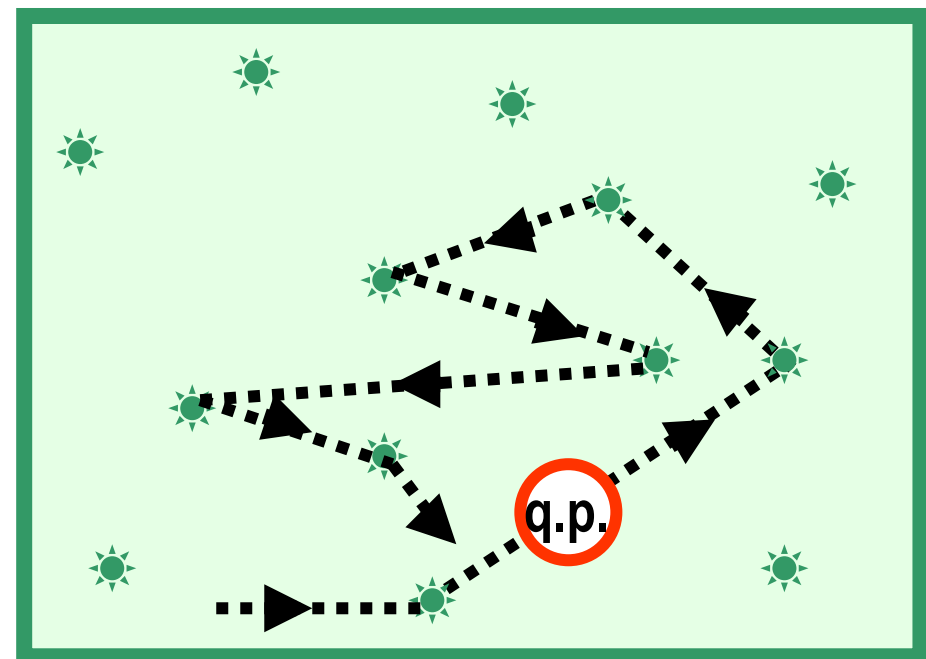
Bell Telephone Laboratories, Murray Hill, New Jersey

(Received October 10, 1957)

This paper presents a simple model for such processes as spin diffusion or conduction in the "impurity band." These processes involve transport in a lattice which is in some sense random, and in them diffusion is expected to take place via quantum jumps between localized sites. In this simple model the essential randomness is introduced by requiring the energy to vary randomly from site to site. It is shown that at low enough densities no diffusion at all can take place, and the criteria for transport to occur are given.



- One quantum particle
- Random potential (e.g., impurities)
Elastic scattering





Einstein (1905):

Random walk



always **diffusion**

as long as the system has no memory

$$\langle r^2 \rangle = Dt$$

diffusion constant



Anderson(1958):

For quantum particles



not always!

It might be that

$$\langle r^2 \rangle \xrightarrow{t \rightarrow \infty} const$$

$$D = 0$$

Quantum interference \Rightarrow memory

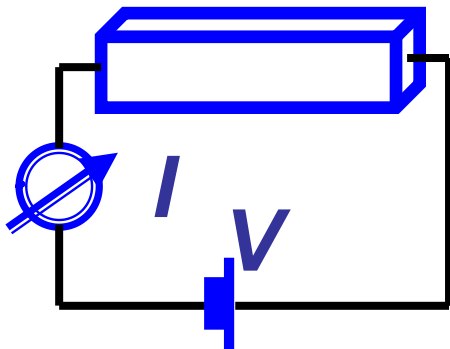
Einstein Relation (1905)

$$\sigma = e^2 D \nu \qquad \nu \equiv \frac{dn}{d\mu}$$

Conductivity

Diffusion Constant

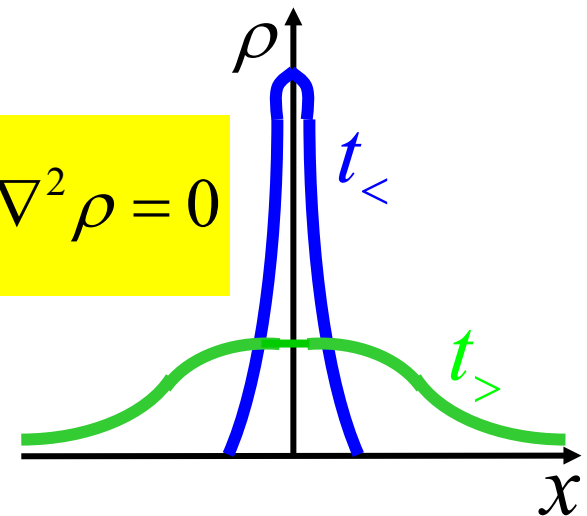
Density of states



$$G = \left(\frac{I}{V} \right)_{V=0} ;$$

$$\sigma = G \frac{L}{A}$$

$$\frac{\partial \rho}{\partial t} - D \nabla^2 \rho = 0$$



Einstein Relation (1905)

$$\sigma = e^2 D \nu \quad \nu \equiv \frac{dn}{d\mu}$$

Conductivity

Diffusion Constant

Density of states

No diffusion - no conductivity

Localized states - insulator

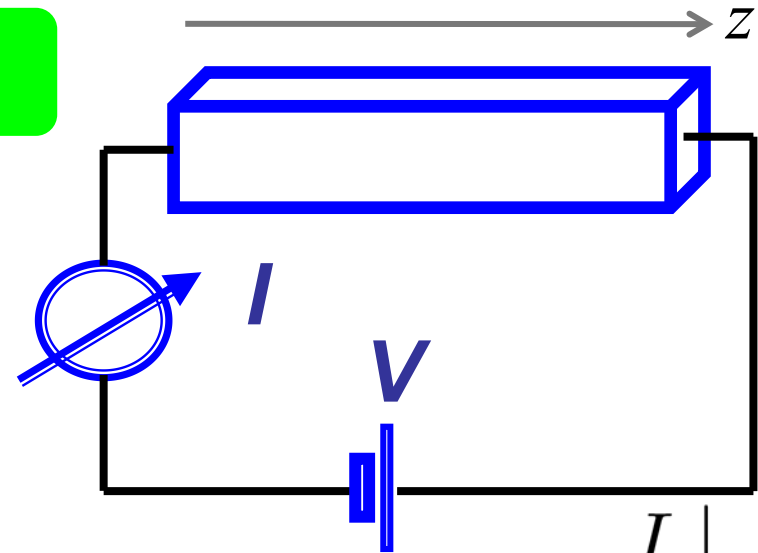
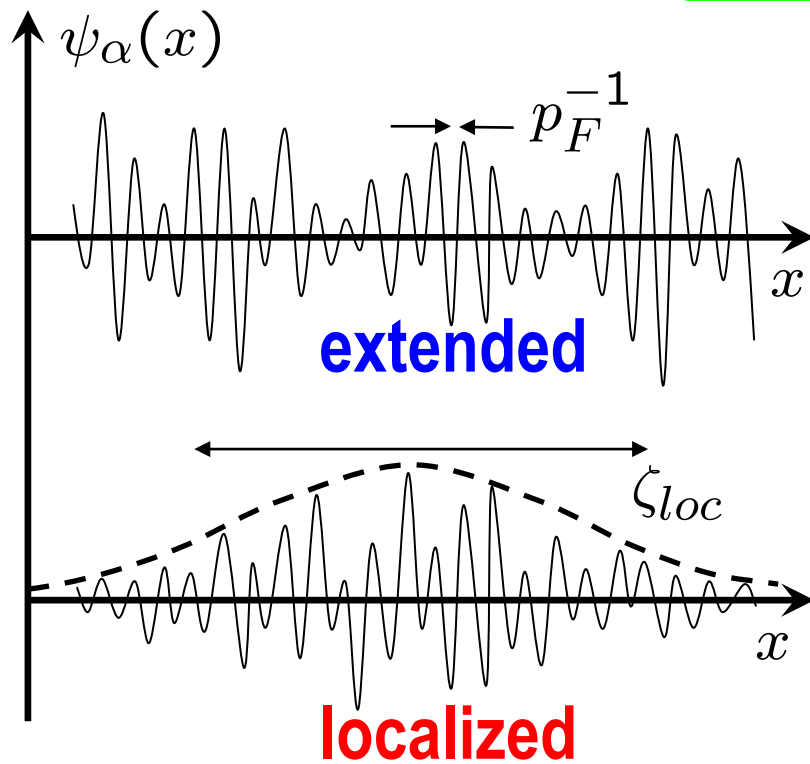
Extended states - metal

Metal - insulator transition

Localization of single-electron wave-functions:

$$\left[-\frac{\nabla^2}{2m} + U(\mathbf{r}) - \epsilon_F \right] \psi_\alpha(\mathbf{r}) = \xi_\alpha \psi_\alpha(\mathbf{r})$$

Disorder



Conductance $G = \frac{I}{V} \Big|_{V \rightarrow 0}$

$$= \begin{cases} \sigma \frac{L_x L_y}{L_z} & \text{extended} \\ \propto \exp\left(\frac{-L_z}{\zeta_{loc}}\right) & \text{localized} \end{cases}$$

Experiment

Spin Diffusion

Feher, G., Phys. Rev. 114, 1219 (1959); Feher, G. & Gere, E. A., Phys. Rev. 114, 1245 (1959).

Light

Wiersma, D.S., Bartolini, P., Lagendijk, A. & Righini R. “Localization of light in a disordered medium”, *Nature* 390, 671-673 (1997).

Scheffold, F., Lenke, R., Tweert, R. & Maret, G. “Localization or classical diffusion of light”, *Nature* 398, 206-270 (1999).

Schwartz, T., Bartal, G., Fishman, S. & Segev, M. “Transport and Anderson localization in disordered two dimensional photonic lattices”. *Nature* 446, 52-55 (2007).

C.M. Aegerter, M. Störzer, S. Fiebig, W. Bührer, and G. Maret : JOSA A, 24, #10, A23, (2007)

Microwave

Dalichaouch, R., Armstrong, J.P., Schultz, S., Platzman, P.M. & McCall, S.L. “Microwave localization by 2-dimensional random scattering”. *Nature* 354, 53, (1991).

Chabanov, A.A., Stoytchev, M. & Genack, A.Z. Statistical signatures of photon localization. *Nature* 404, 850, (2000).

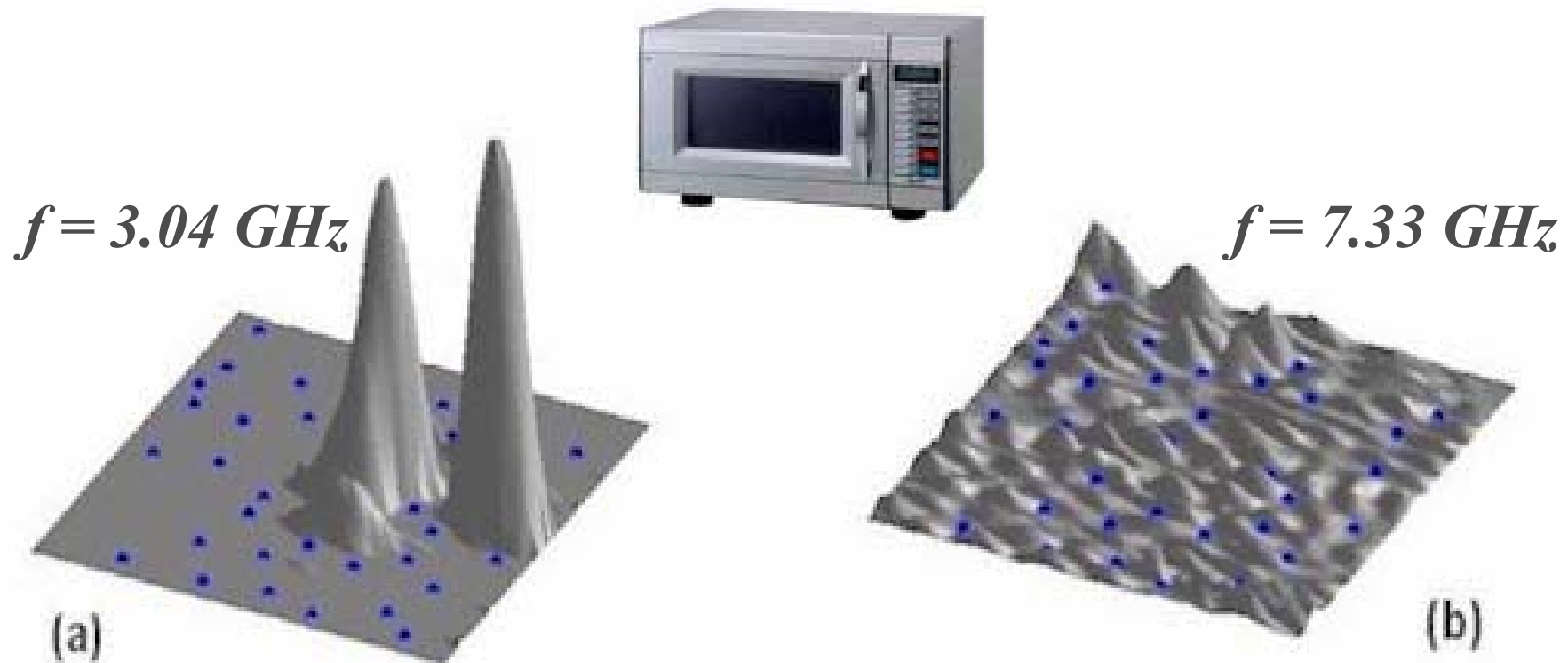
Pradhan, P., Sridar, S, “Correlations due to localization in quantum eigenfunctions of disordered microwave cavities”, PRL 85, (2000)

Sound

Weaver, R.L. Anderson localization of ultrasound. *Wave Motion* 12, 129-142 (1990).

Correlations due to Localization in Quantum Eigenfunctions of Disordered Microwave Cavities

Prabhakar Pradhan and S. Sridhar

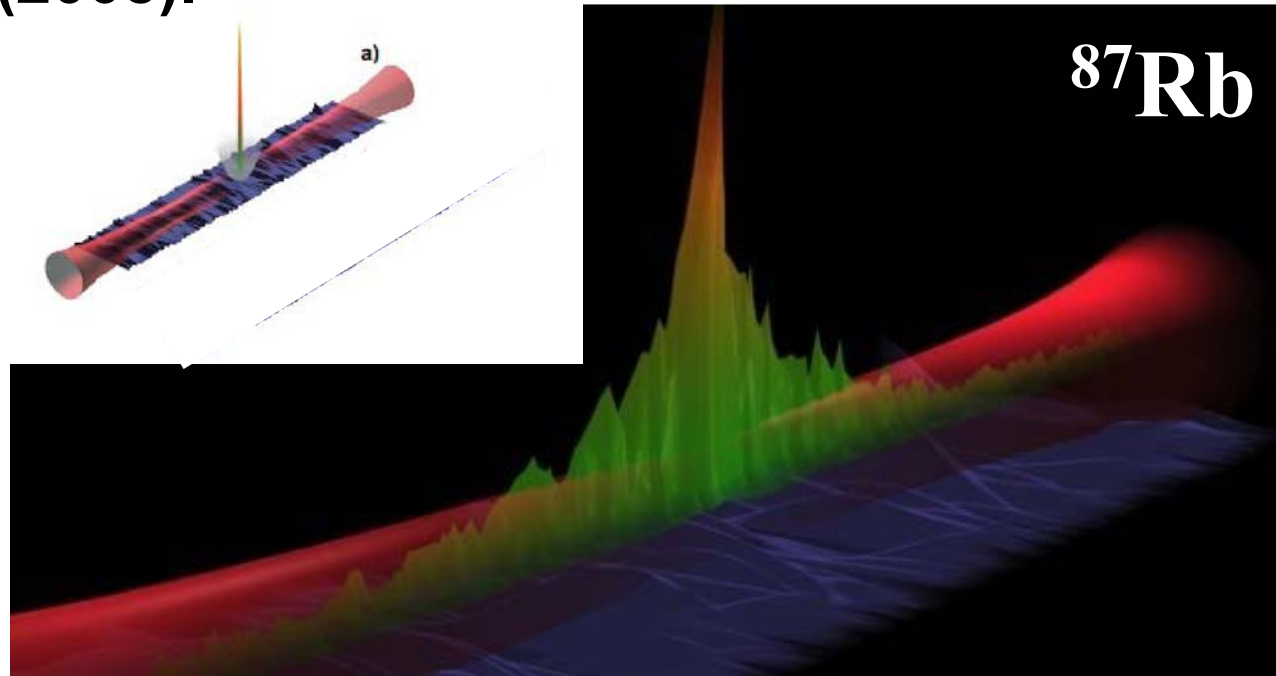
*Department of Physics, Northeastern University, Boston, Massachusetts 02115**(Received 28 February 2000)*

Localized State
Anderson Insulator

Extended State
Anderson Metal

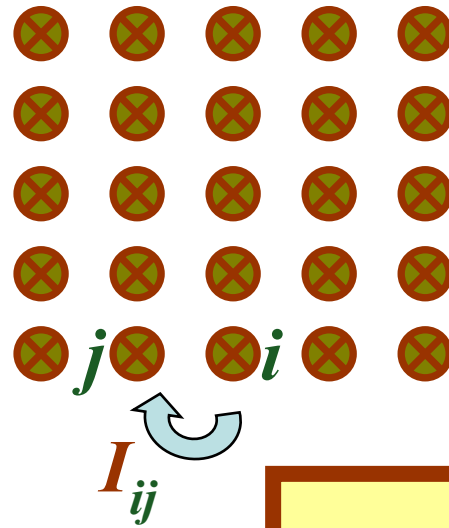
Localization of cold atoms

Billy et al. “Direct observation of Anderson localization of matter waves in a controlled disorder”. Nature 453, 891- 894 (2008).



Roati et al. “Anderson localization of a non-interacting Bose-Einstein condensate”. Nature 453, 895-898 (2008).

Anderson Model



- Lattice - tight binding model
- Onsite energies ϵ_i - *random*
- Hopping matrix elements I_{ij}

$$-W < \epsilon_i < W$$

uniformly distributed

$$I_{ij} = \begin{cases} I & \mathbf{i} \text{ and } \mathbf{j} \text{ are nearest neighbors} \\ 0 & \text{otherwise} \end{cases}$$

Anderson Transition

$$I < I_c$$

Insulator

All eigenstates are localized
Localization length ξ

$$I > I_c$$

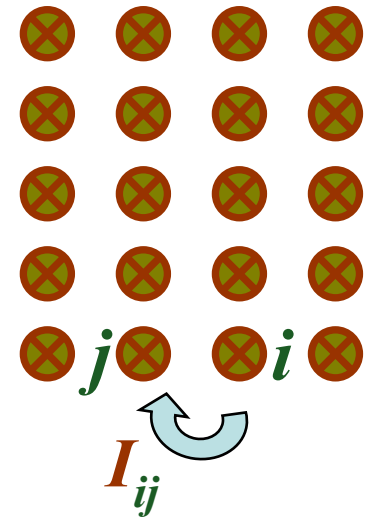
Metal

There appear states extended
all over the whole system

Q

- Why arbitrary
- weak hopping I is not sufficient for the existence of the diffusion

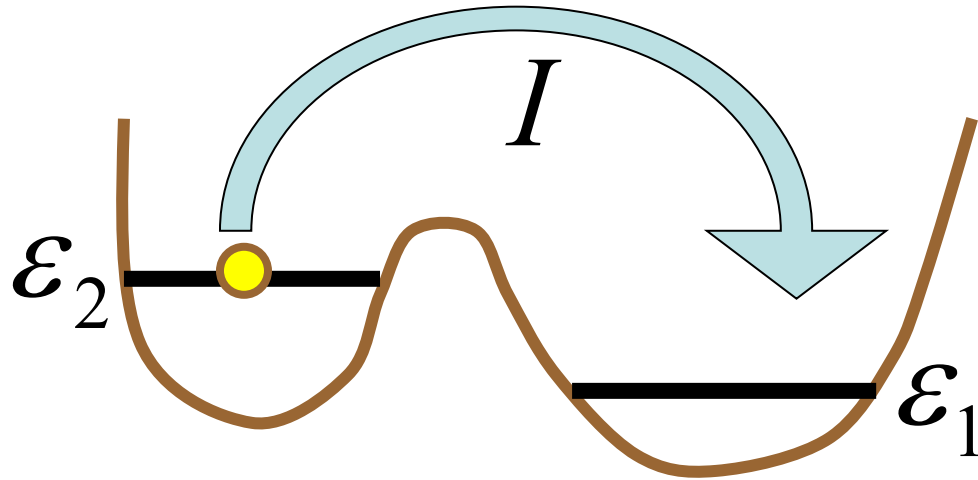
?



Einstein (1905): Markovian (no memory) process \rightarrow diffusion

Quantum mechanics is not Markovian!
There is memory in quantum propagation!

Why?



Hamiltonian

$$\hat{H} = \begin{pmatrix} \varepsilon_1 & I \\ I & \varepsilon_2 \end{pmatrix} \xrightarrow{\text{diagonalize}} \hat{H} = \begin{pmatrix} E_1 & 0 \\ 0 & E_2 \end{pmatrix}$$

$$E_2 - E_1 = \sqrt{(\varepsilon_2 - \varepsilon_1)^2 + I^2}$$

$$\hat{H} = \begin{pmatrix} \varepsilon_1 & I \\ I & \varepsilon_2 \end{pmatrix} \quad E_2 - E_1 = \sqrt{(\varepsilon_2 - \varepsilon_1)^2 + I^2} \approx \begin{matrix} \varepsilon_2 - \varepsilon_1 & \varepsilon_2 - \varepsilon_1 \gg I \\ I & \varepsilon_2 - \varepsilon_1 \ll I \end{matrix}$$

What about the eigenfunctions ?

$$\phi_1, \varepsilon_1; \phi_2, \varepsilon_2 \quad \Leftarrow \quad \psi_1, E_1; \psi_2, E_2$$

$$\varepsilon_2 - \varepsilon_1 \gg I$$

$$\psi_{1,2} = \varphi_{1,2} + O\left(\frac{I}{\varepsilon_2 - \varepsilon_1}\right)\varphi_{2,1}$$

Off-resonance

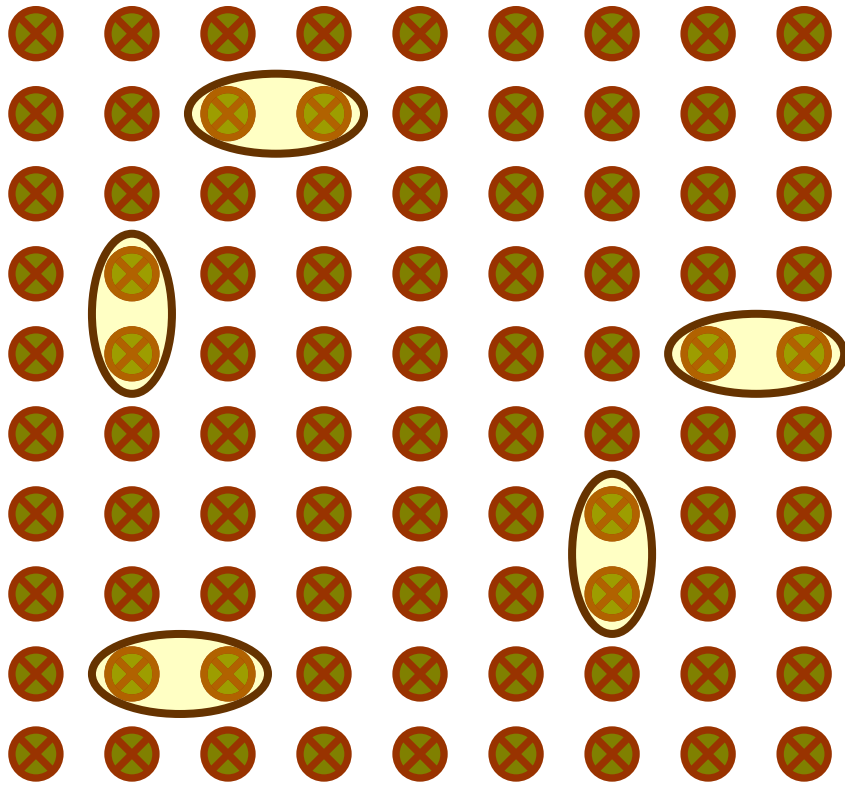
Eigenfunctions are close to the original on-site wave functions

$$\varepsilon_2 - \varepsilon_1 \ll I$$

$$\psi_{1,2} \approx \varphi_{1,2} \pm \varphi_{2,1}$$

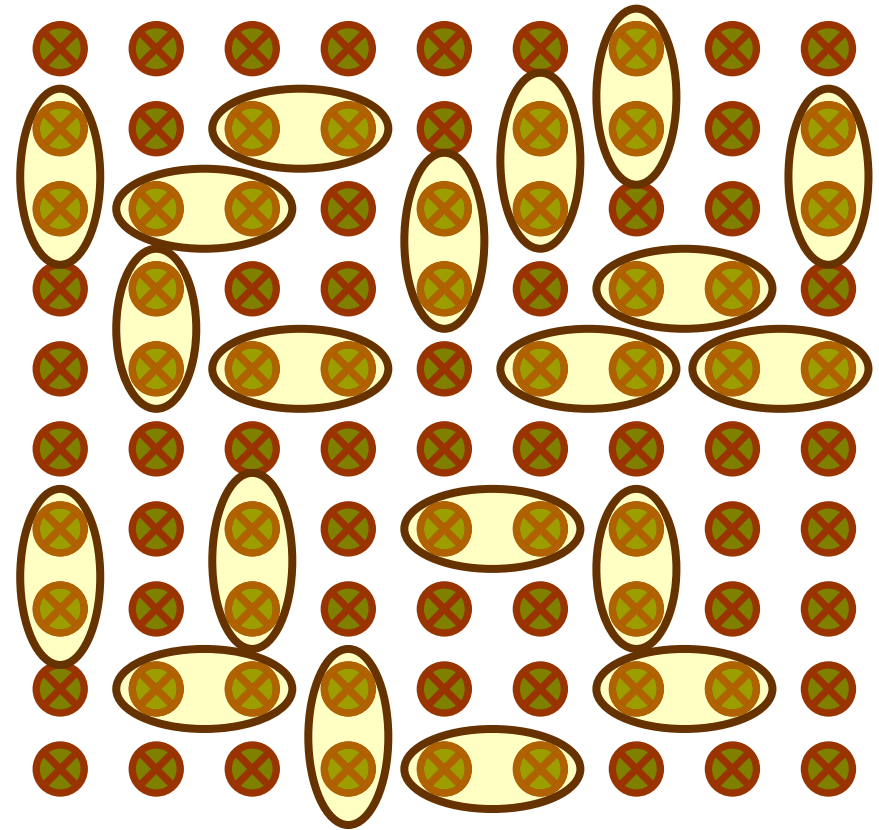
Resonance

In both eigenstates the probability is equally shared between the sites



Anderson insulator

Few isolated resonances



Anderson metal

There are many resonances
and they overlap

Transition:

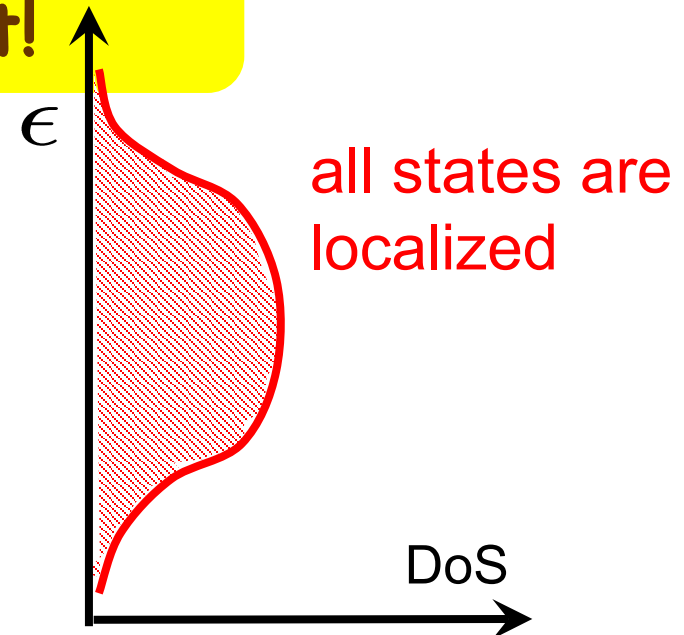
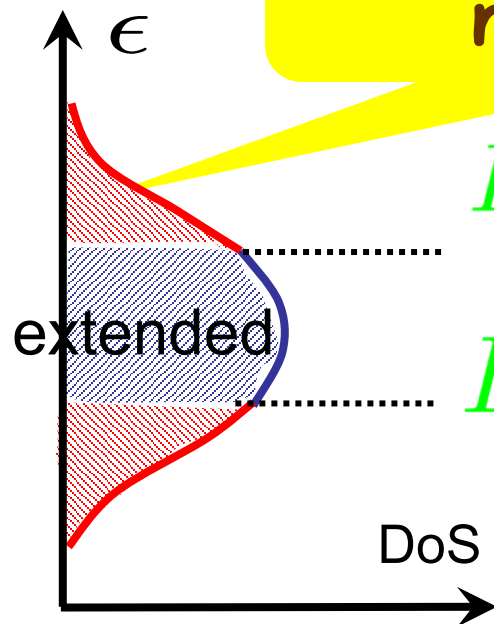
Typically each site is in
resonance with some other one

Anderson Transition

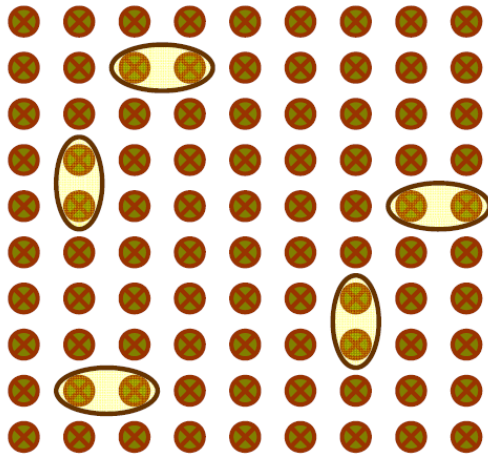
$$I > I_c$$

$$I < I_c$$

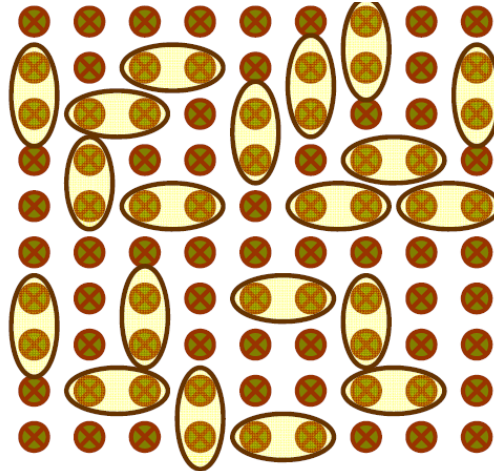
localized and extended
never coexist!



E_c - mobility edges (one particle)



Anderson insulator
Few isolated resonances



Anderson metal
There are many resonances and they overlap

Condition for Localization:

$$I < \frac{\text{energy mismatch}}{\# \text{ of n.neighbors}}$$

$$\text{energy mismatch} = |\varepsilon_i - \varepsilon_j|_{typ} = W$$

$$\# \text{ of nearest neighbors} = 2d$$

Transition: Typically each site is in resonance with some other one

A bit more precise:

$$\frac{I_c}{W} \approx \left(\frac{1}{2d} \right) \left(\frac{1}{\ln d} \right)$$

Logarithm is due to the resonances, which are not nearest neighbors

Condition for Localization:

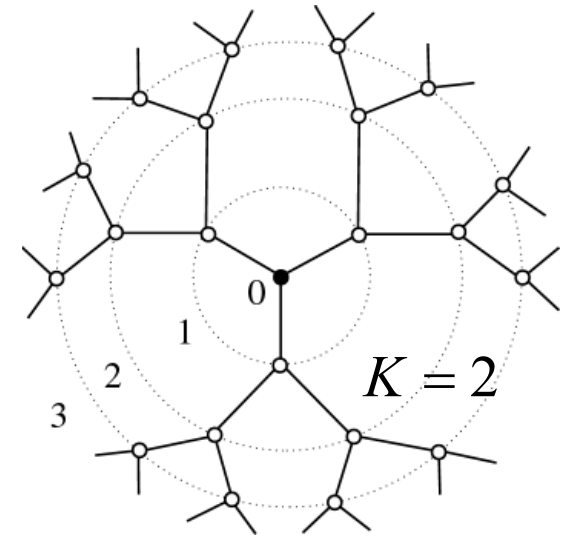
$$\frac{I_c}{W} \approx \left(\frac{1}{2d} \right) \left(\frac{1}{\ln d} \right)$$

Q: Is it correct?

A1: Is exact on the Cayley tree

$$I_c = \frac{W}{K \ln K},$$

K is the
branching
number



Anderson Model on a Cayley tree

A selfconsistent theory of localization

R Abou-Chacra†, P W Anderson‡§ and D J Thouless†

† Department of Mathematical Physics, University of Birmingham, Birmingham, B15 2TT

‡ Cavendish Laboratory, Cambridge, England and Bell Laboratories, Murray Hill, New Jersey, 07974, USA

Received 12 January 1973

Abstract. A new basis has been found for the theory of localization of electrons in disordered systems. The method is based on a selfconsistent solution of the equation for the self energy in second order perturbation theory, whose solution may be purely real almost everywhere (localized states) or complex everywhere (nonlocalized states). The equations used are exact for a Bethe lattice. The selfconsistency condition gives a nonlinear integral equation in two variables for the probability distribution of the real and imaginary parts of the self energy. A simple approximation for the stability limit of localized states gives Anderson's 'upper limit approximation'. Exact solution of the stability problem in a special case gives results very close to Anderson's best estimate. A general and simple formula for the stability limit is derived; this formula should be valid for smooth distribution of site energies away from the band edge. Results of Monte Carlo calculations of the selfconsistency problem are described which confirm and go beyond the analytical results. The relation of this theory to the old Anderson theory is examined, and it is concluded that the present theory is similar but better.

Condition for Localization:

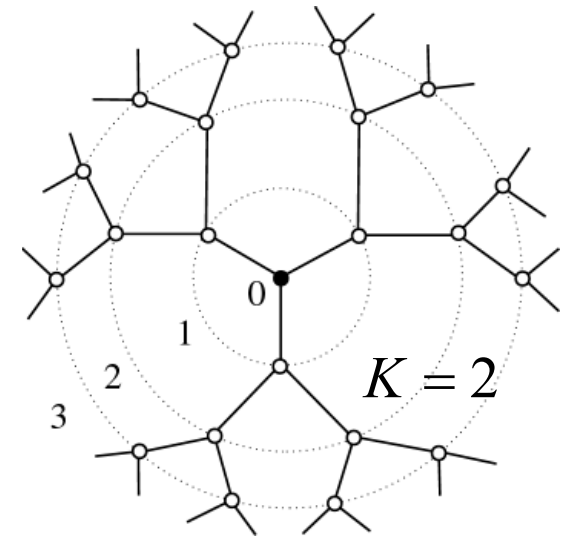
$$\frac{I_c}{W} \approx \left(\frac{1}{2d} \right) \left(\frac{1}{\ln d} \right)$$

Q: Is it correct?

A1: Is exact on the Cayley tree

$$I_c = \frac{W}{K \ln K},$$

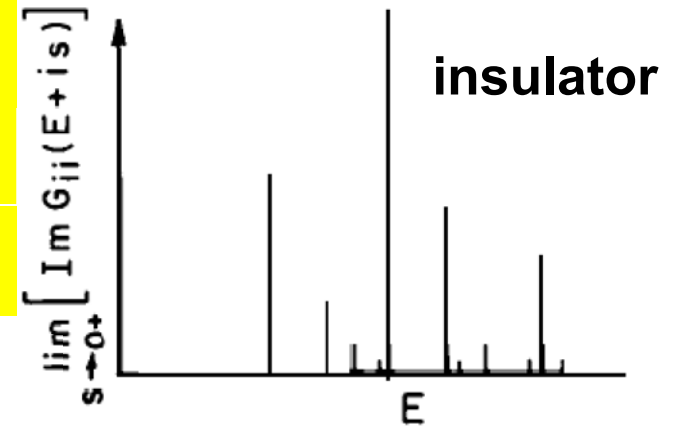
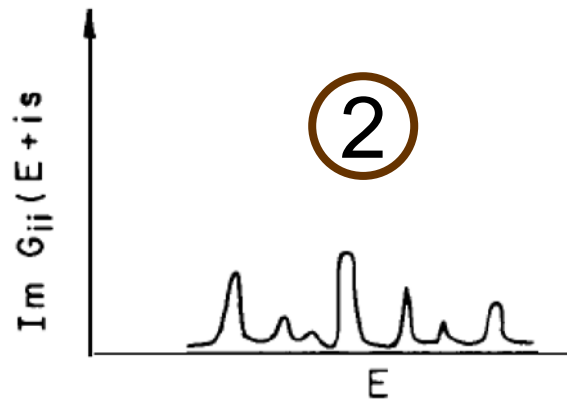
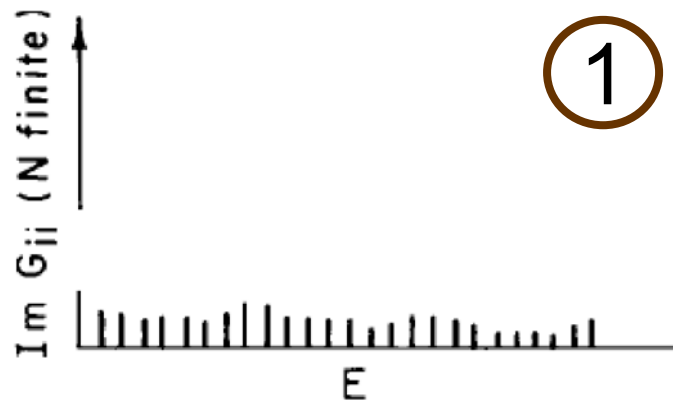
K is the
branching
number



A1': Is a good approximation at high dimensions.
Is qualitatively correct for $d \geq 3$

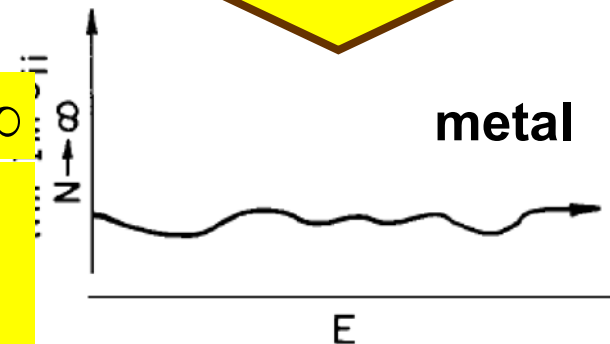
Anderson's recipe:

1. take discrete spectrum E_μ of H_0
2. Add an infinitesimal *Im* part $i\eta$ to E_μ
3. Evaluate $Im\Sigma_\mu$

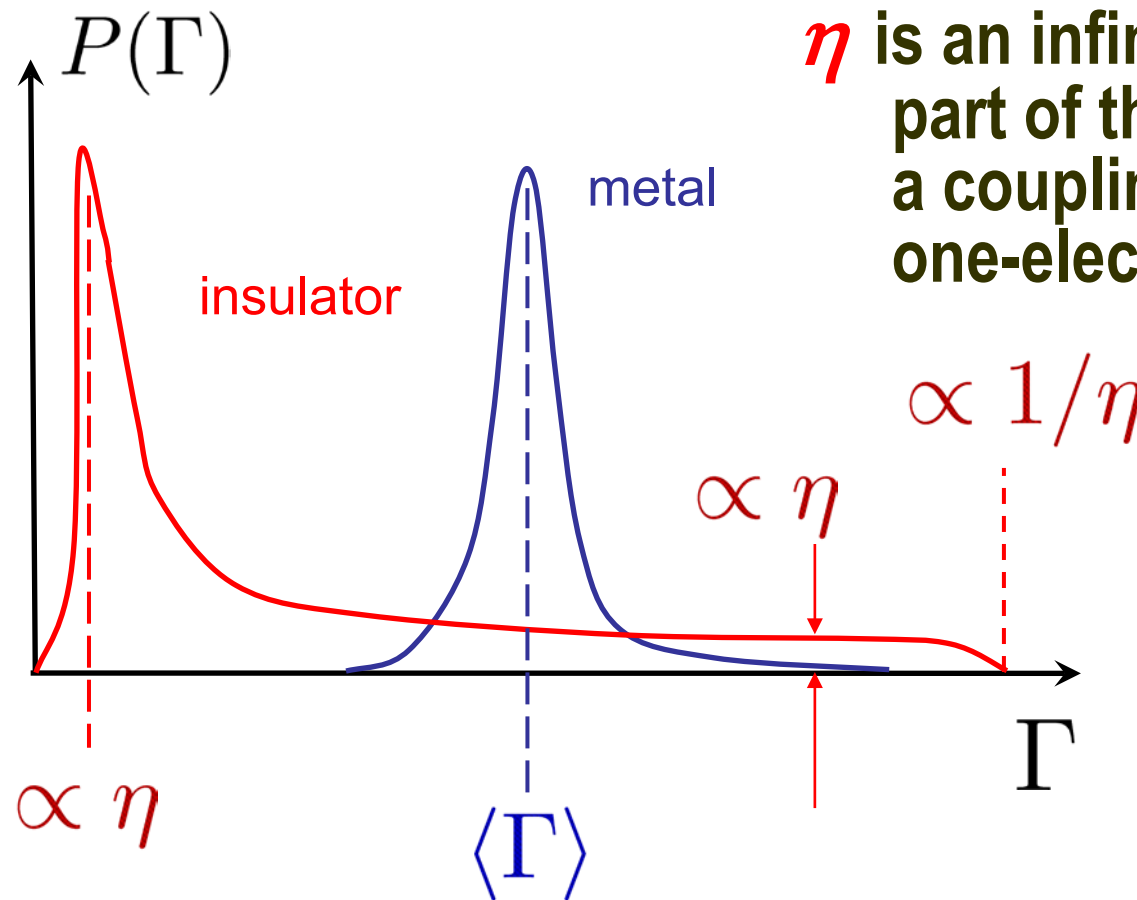


④ **limits**
 1) $N \rightarrow \infty$
 2) $\eta \rightarrow 0$

4. take limit $\eta \rightarrow 0$ but only **after** $N \rightarrow \infty$
5. "What we really need to know is the *probability distribution* of $Im\Sigma$, **not** its average..."



Probability Distribution of $\Gamma = \text{Im} \Sigma$



η is an infinitesimal width (*Im* part of the self-energy due to a coupling with a bath) of one-electron eigenstates

Look for:

$$\lim_{\eta \rightarrow +0} \lim_{V \rightarrow \infty} P(\Gamma > 0) = \begin{cases} > 0; & \text{metal} \\ 0; & \text{insulator} \end{cases}$$

Condition for Localization:

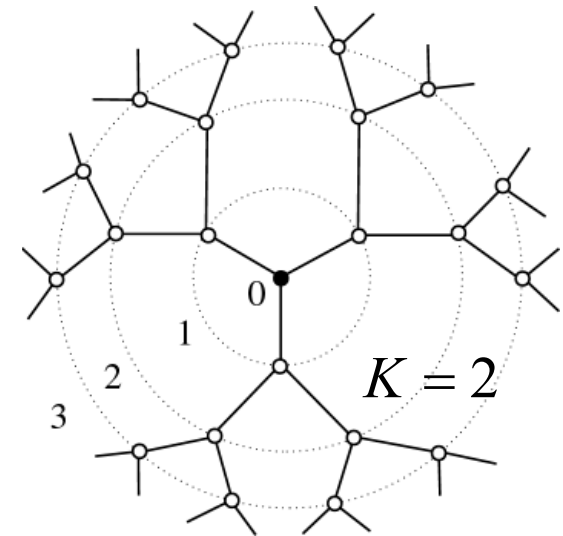
$$\frac{I_c}{W} \approx \left(\frac{1}{2d} \right) \left(\frac{1}{\ln d} \right)$$

Q: Is it correct?

A1: Is exact on the Cayley tree

$$I_c = \frac{W}{K \ln K},$$

K is the
branching
number



A1': Is a good approximation at high dimensions.
Is qualitatively correct for $d \geq 3$

A2: For low dimensions - **NO**. $I_c = \infty$ for $d = 1, 2$
All states are localized. Reason - loop trajectories

1D Localization

Exactly solved:
all states are localized

Gertsenshtein & Vasil'ev,
1959

Conjectured:

Mott & Twose, 1961

-
-
-

Condition for Localization:

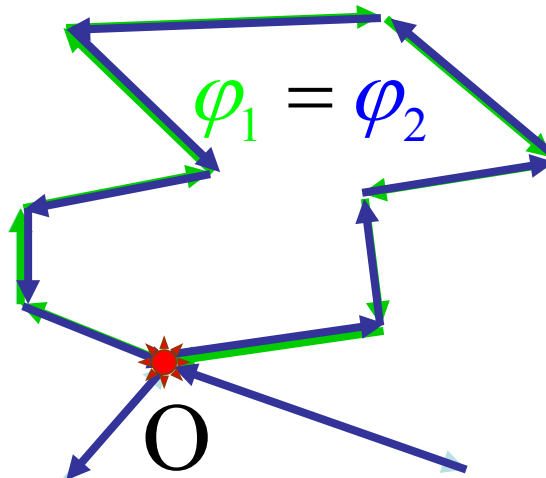
$$\frac{I_c}{W} \approx \left(\frac{1}{2d} \right) \left(\frac{1}{\ln d} \right)$$

Q: Is it correct?

A2: For low dimensions - **NO**. $I_c = \infty$ for $d = 1, 2$
All states are localized. Reason - loop trajectories

$$\varphi = \oint \vec{p} d\vec{r}$$

Phase accumulated
when traveling
along the loop

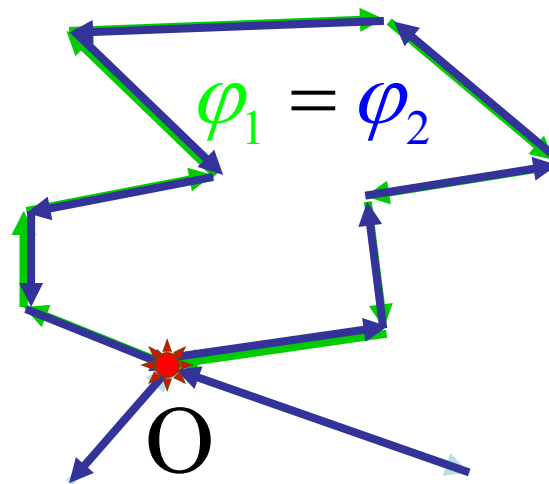


The particle
can go around
the loop in
two directions

Memory!

Einstein: there is no diffusion at too **short** scales - there is memory, i.e., the process is **not marcovian**.

Due to the localization effects diffusion description fails at **large** scales.
Quantum interference \longrightarrow Memory



Large scales are important \longrightarrow diffusion constant depends on the system size

Einstein relation for the conductivity σ

$$\sigma = e^2 D \nu \quad \nu \equiv \frac{dn}{d\mu}$$

Conductance

$$G = \sigma L^{d-2}$$

for a cubic sample of the size L

$$G = \frac{e^2}{h} \underbrace{(\nu L^d)}_{g(L)} \frac{Dh}{L^2}$$

$$g(L) = \frac{hD/L^2}{1/\nu L^d}$$

$$= \frac{\text{Thouless energy}}{\text{mean level spacing}}$$

**Dimensionless
Thouless
conductance**

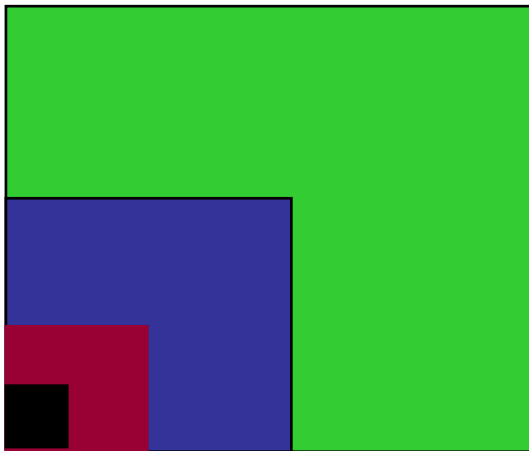
Scaling theory of Localization

(Abrahams, Anderson, Licciardello and Ramakrishnan
1979)

$$g = E_T / \delta_1$$

Dimensionless *Thouless*
conductance

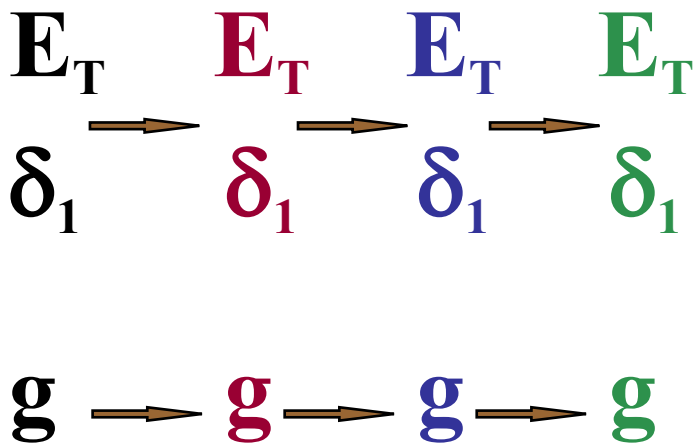
$$g = Gh/e^2$$



$$L = 2L = 4L = 8L \dots$$

without quantum corrections

$$E_T \propto L^{-2} \quad \delta_1 \propto L^{-d}$$



$$\frac{d(\log g)}{d(\log L)} = \beta(g)$$

$$\frac{d(\log g)}{d(\log L)} = \beta(g)$$

Universal, i.e., material independent

But

β – function is

It depends on the global symmetries, e.g., it is different with and without **T-invariance** (in orthogonal and unitary ensembles)

Limits:

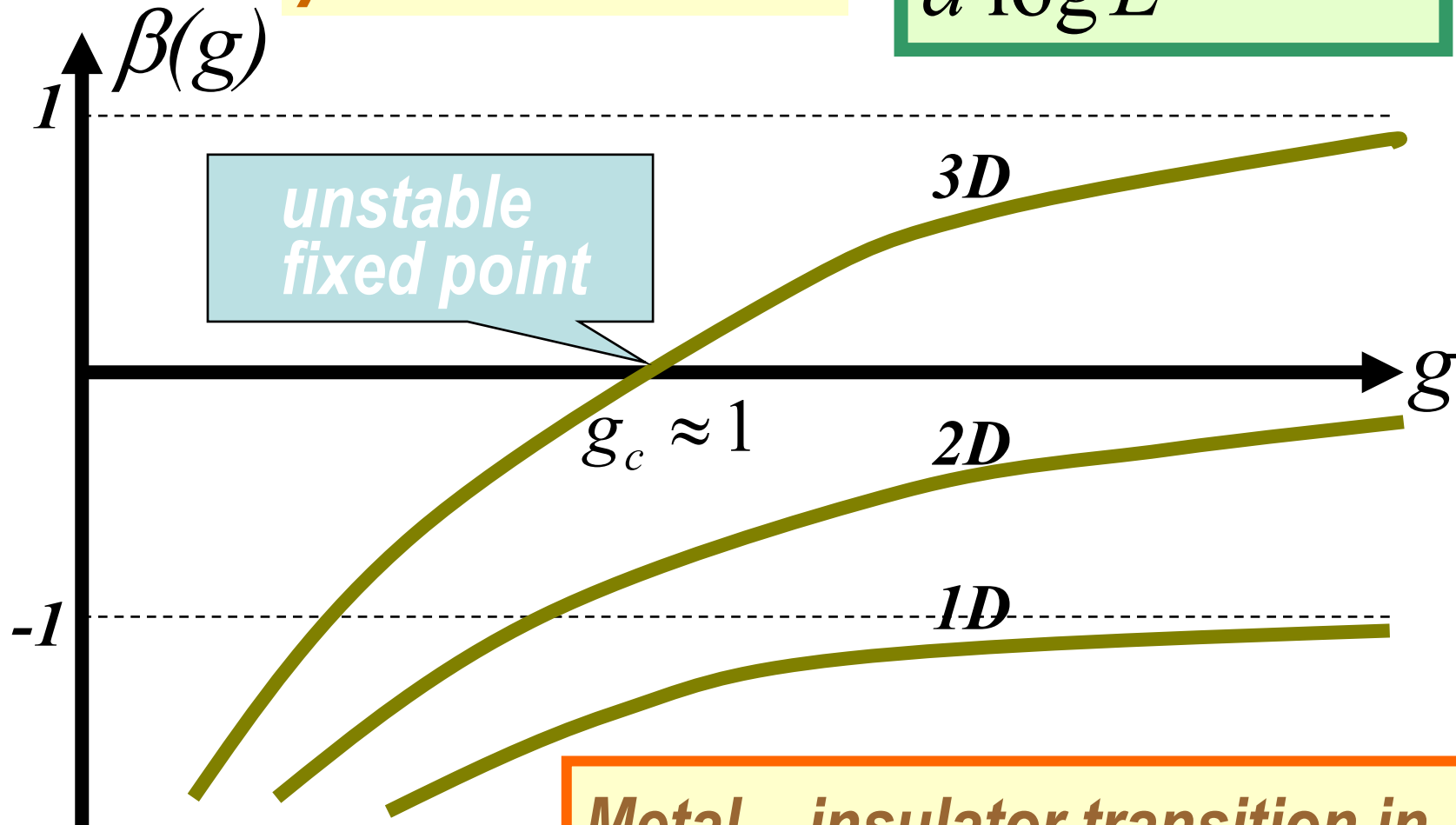
$$g \gg 1 \quad g \propto L^{d-2} \quad \beta(g) = (d-2) + O\left(\frac{1}{g}\right)$$

$$\begin{array}{ll} > 0 & d > 2 \\ ?? & d = 2 \\ < 0 & d < 2 \end{array}$$

$$g \ll 1 \quad g \propto e^{-L/\xi} \quad \beta(g) \approx \log g < 0$$

β - function

$$\frac{d \log g}{d \log L} = \beta(g)$$



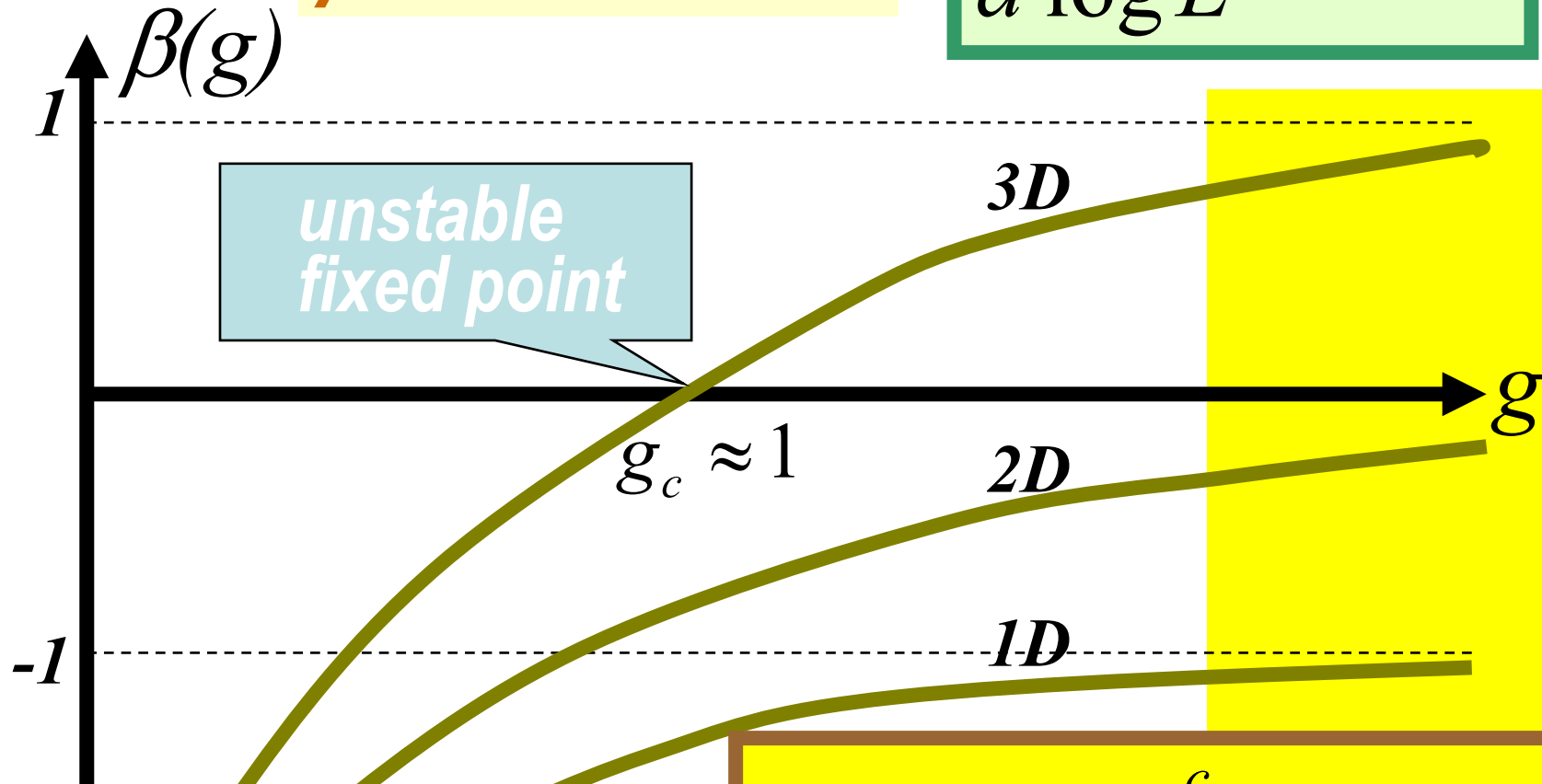
Metal – insulator transition in 3D
All states are localized for $d=1,2$

RG approach

Effective Field Theory of Localization -
Nonlinear σ - model

β - function

$$\frac{d \log g}{d \log L} = \beta(g)$$



$$\beta(g) = d - 2 + \frac{c_d}{g}$$

$c_d = ? \quad \pm ?$

$$g(L) = \sigma_{c_d} L^{d-2} - \frac{c_d}{d-2} \quad d \neq 2$$

$$c_2 \log\left(\frac{L}{l}\right) \quad d = 2$$

$$P(t) = \hat{\lambda}^{d-1} \int_{\tau}^t \frac{v_F dt'}{(Dt')^{d/2}}$$

$$\frac{\delta g}{g} \approx P(t_{\max})$$

$$\frac{\delta g}{g} \approx -\frac{\hat{\lambda} v_F}{D} \log \frac{L^2}{D\tau} = -\frac{2\hat{\lambda} v_F}{D} \log \frac{L}{l}$$

$$\hat{\lambda} v_F = \frac{1}{\pi v}$$

$$g = v D \hbar$$

$$\delta g = -\frac{2}{\pi} \log \frac{L}{l}$$

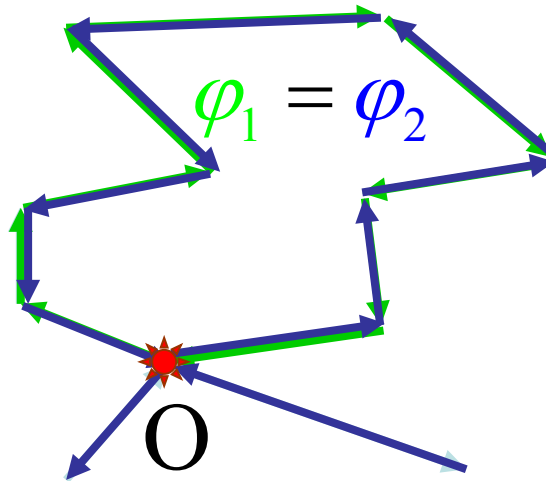
$$\beta(g) = -\frac{2}{\pi g}$$

Universal !!!

For $d=1,2$ all states are localized.

$$\varphi = \oint \vec{p} d\vec{r}$$

Phase accumulated
when traveling
along the loop



The particle
can go around
the loop in
two directions

Memory!

Weak Localization:

The localization length ζ can be large

Inelastic processes lead to dephasing, which is characterized by the dephasing length L_φ

If $\zeta \gg L_\varphi$, then only small corrections to a conventional metallic behavior

ОБ ИЗМЕНЕНИИ ЭЛЕКТРИЧЕСКОГО СОПРОТИВЛЕНИЯ ТЕЛЛУРА В МАГНИТНОМ ПОЛЕ ПРИ НИЗКИХ ТЕМПЕРАТУРАХ

Р. А. Ченцов

R.A. Chentsov *“On the variation of electrical resistivity of tellurium in magnetic field at low temperatures”*, Zh. Exp. Theor. Fiz. v.18, 375-385, (1948).

Таблица 2

Уменьшение сопротивления теллура
в магнитном поле

Образец	Температура (°K)	Максимальное уменьшение сопро- тивления
Te-1	2,13	$0,7 \cdot 10^{-3}$
Te-2	2,15	$1,0 \cdot 10^{-3}$
Te-4	1,96	$1,1 \cdot 10^{-3}$
Te-5	1,96	$0,5 \cdot 10^{-3}$

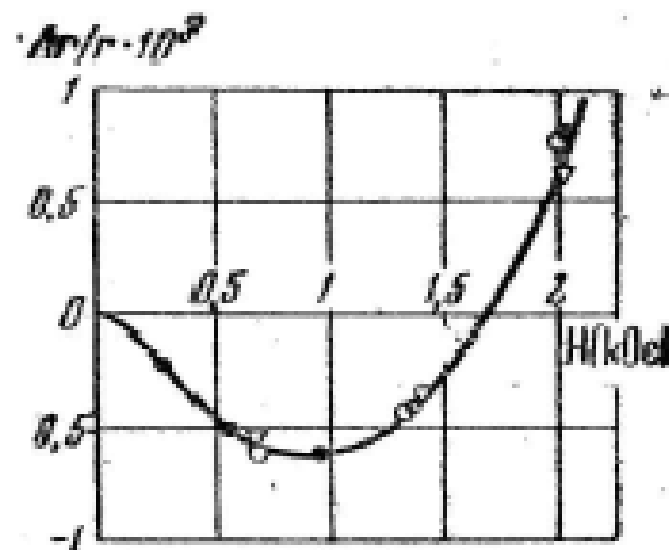
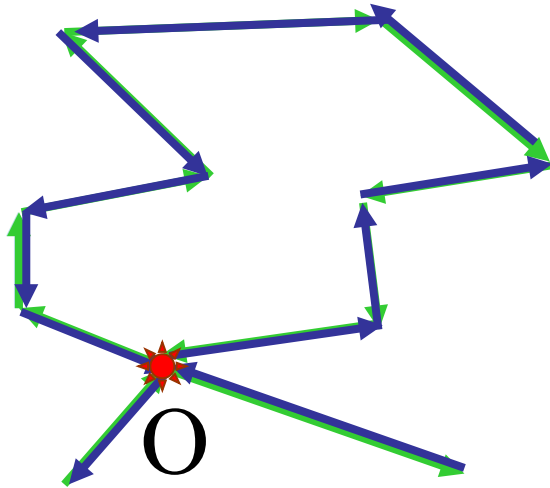


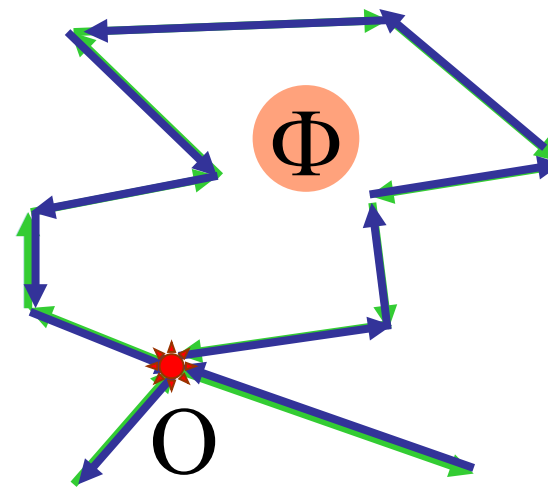
Рис. 2

Magnetoresistance



No magnetic field

$$\varphi_1 = \varphi_2$$



With magnetic field H

$$\varphi_1 - \varphi_2 = 2 * 2\pi \Phi / \Phi_0$$

Length Scales

Magnetic length

$$L_H = (hc/eH)^{1/2}$$

Dephasing length

$$L_\varphi = (D \tau_\varphi)^{1/2}$$



$$\delta g(H) = f_d \left(\frac{L_H}{L_\varphi} \right)$$

Universal
functions

Magnetoresistance measurements allow to study inelastic collisions of electrons with phonons and other electrons

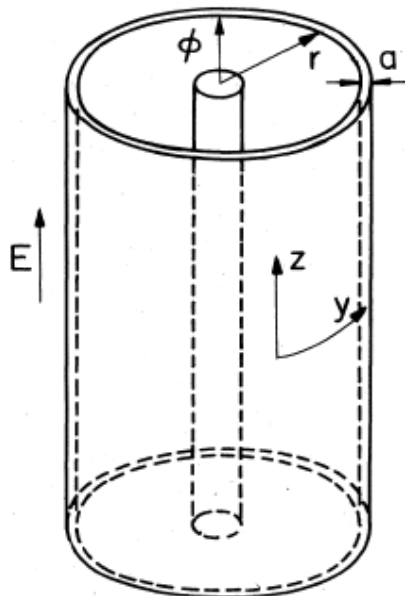
Weak Localization

Negative
Magnetoresistance

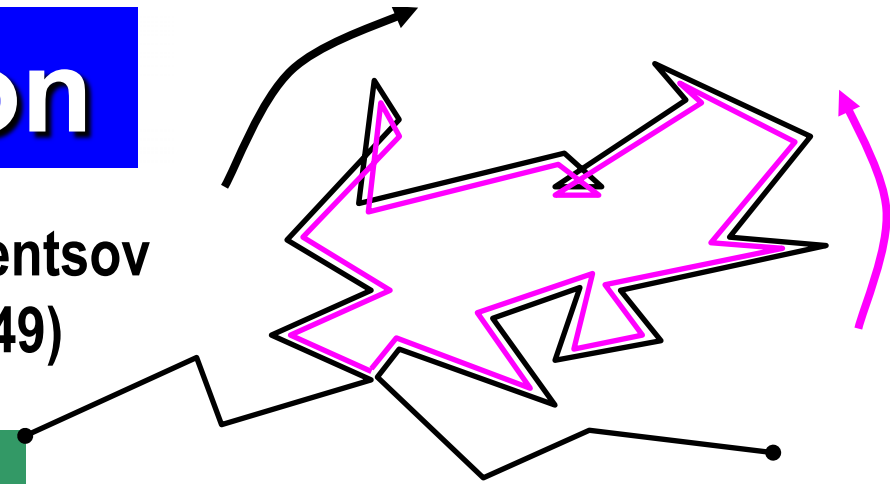
Aharonov-Bohm effect

Theory

B.A., Aronov & Spivak (1981)



Chentsov
(1949)



Experiment

Sharvin & Sharvin (1981)

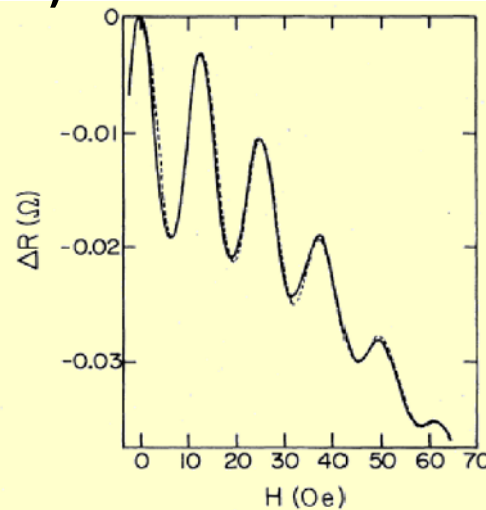
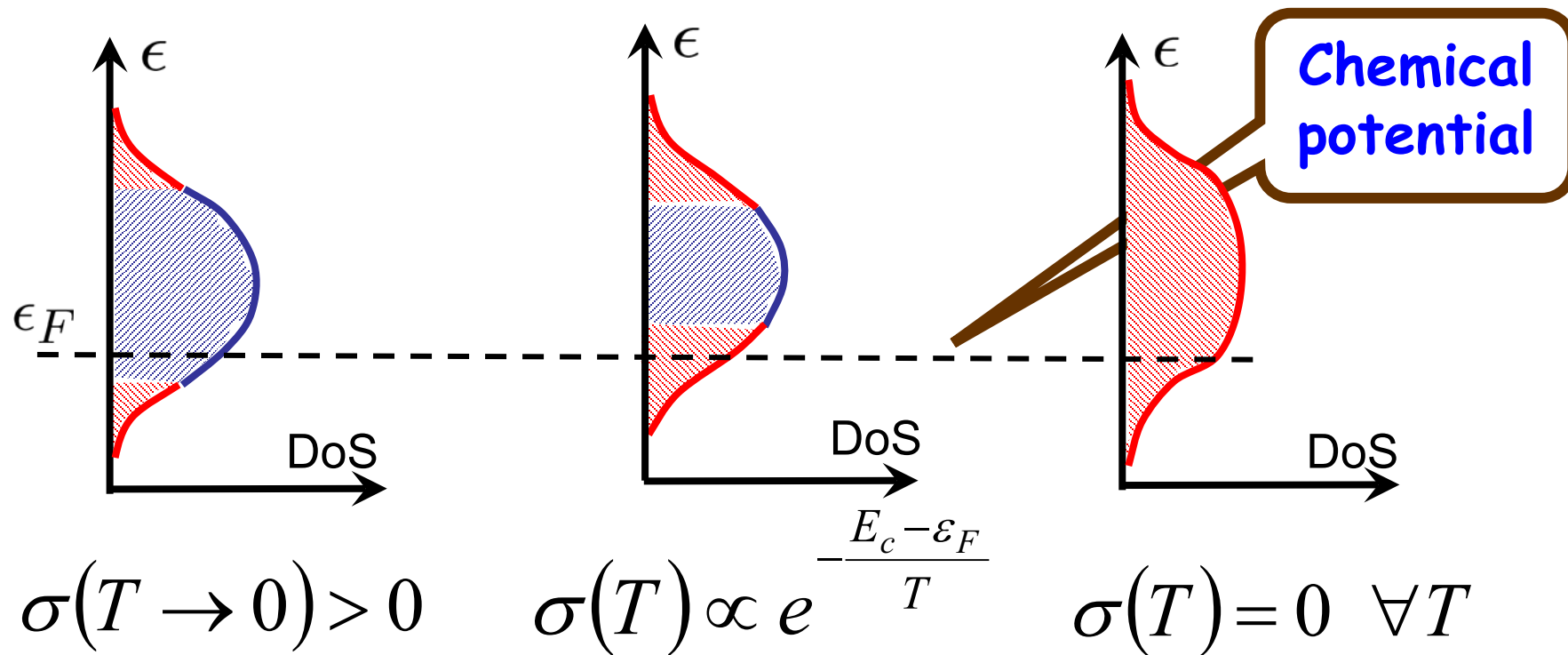


FIG. 8. Longitudinal magnetoresistance $\Delta R(H)$ at $T=1.1$ K for a cylindrical lithium film evaporated onto a 1-cm-long quartz filament. $R_{4,2}=2$ k Ω , $R_{300}/R_{4,2}=2.8$. Solid line: averaged from four experimental curves. Dashed line: calculated for $L_{\phi}=2.2$ μm , $\tau_{\phi}/\tau_{s0}=0$, filament diameter $d=1.31$ μm , film thickness 127 nm. Filament diameter measured with scanning electron microscope yields $d=1.30\pm 0.03$ μm (Altshuler *et al.*, 1982; Sharvin, 1984).

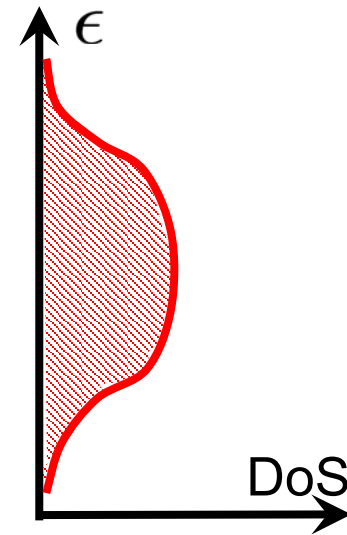


Temperature dependence of the conductivity one-electron picture



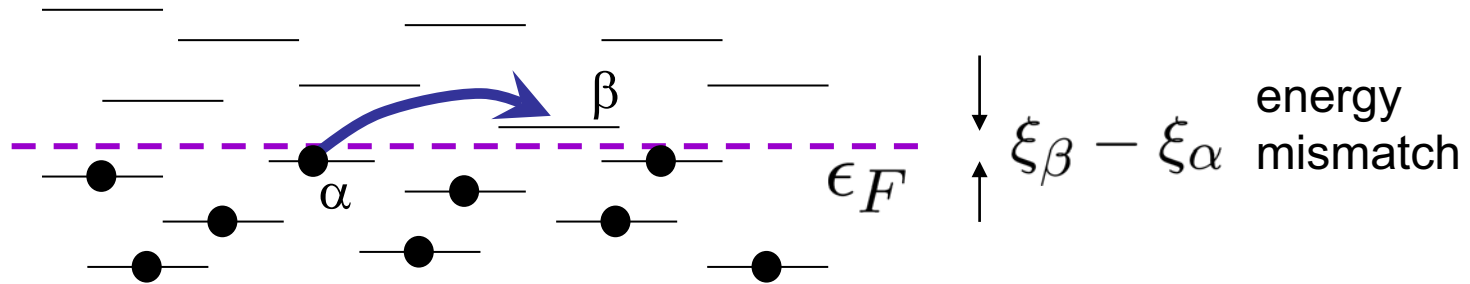
Temperature dependence of the conductivity one-electron picture

Assume that all the
states
are **localized**;
e.g. $d = 1, 2$



$$\sigma(T) = 0 \quad \forall T$$

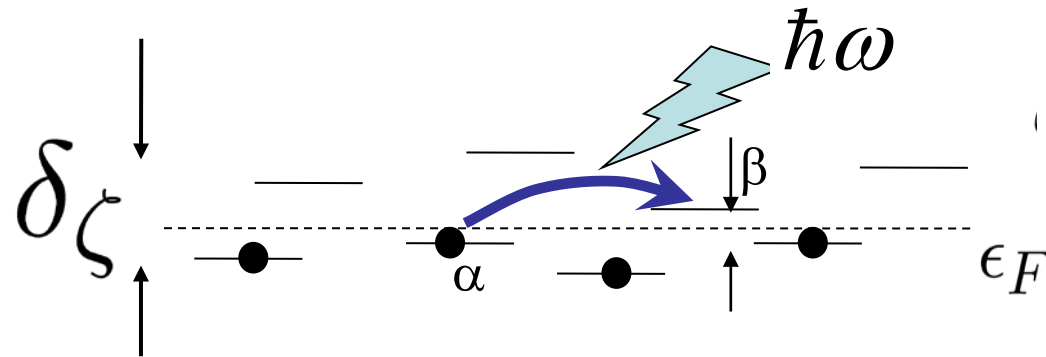
Inelastic processes transitions between localized states



$$T = 0 \quad \Rightarrow \quad \sigma = 0$$

(any mechanism)

Phonon-assisted hopping



$$\hbar\omega = \varepsilon_\alpha - \varepsilon_\beta$$

$$\sigma(T=0) = 0$$

Variable Range
Hopping
N.F. Mott (1968)

$$\sigma(T) \propto T^\gamma \exp \left[- \left(\frac{\delta\zeta}{T} \right)^{\frac{1}{d+1}} \right]$$

Mechanism-dependent
prefactor

Optimized
phase volume

Any bath with a continuous spectrum of **delocalized excitations** down to $\omega = 0$ will give the same exponential

Spectral statistics and Localization

RANDOM MATRIX THEORY

Spectral
statistics

$N \times N$

ensemble of Hermitian matrices
with *random* matrix element

$N \rightarrow \infty$

E_α

- spectrum (set of eigenvalues)

$\delta_1 \equiv \langle E_{\alpha+1} - E_\alpha \rangle$

- mean level spacing,
determines the density of states

$\langle \dots \rangle$

- ensemble averaging

$s \equiv \frac{E_{\alpha+1} - E_\alpha}{\delta_1}$

- spacing between nearest
neighbors

$P(s)$

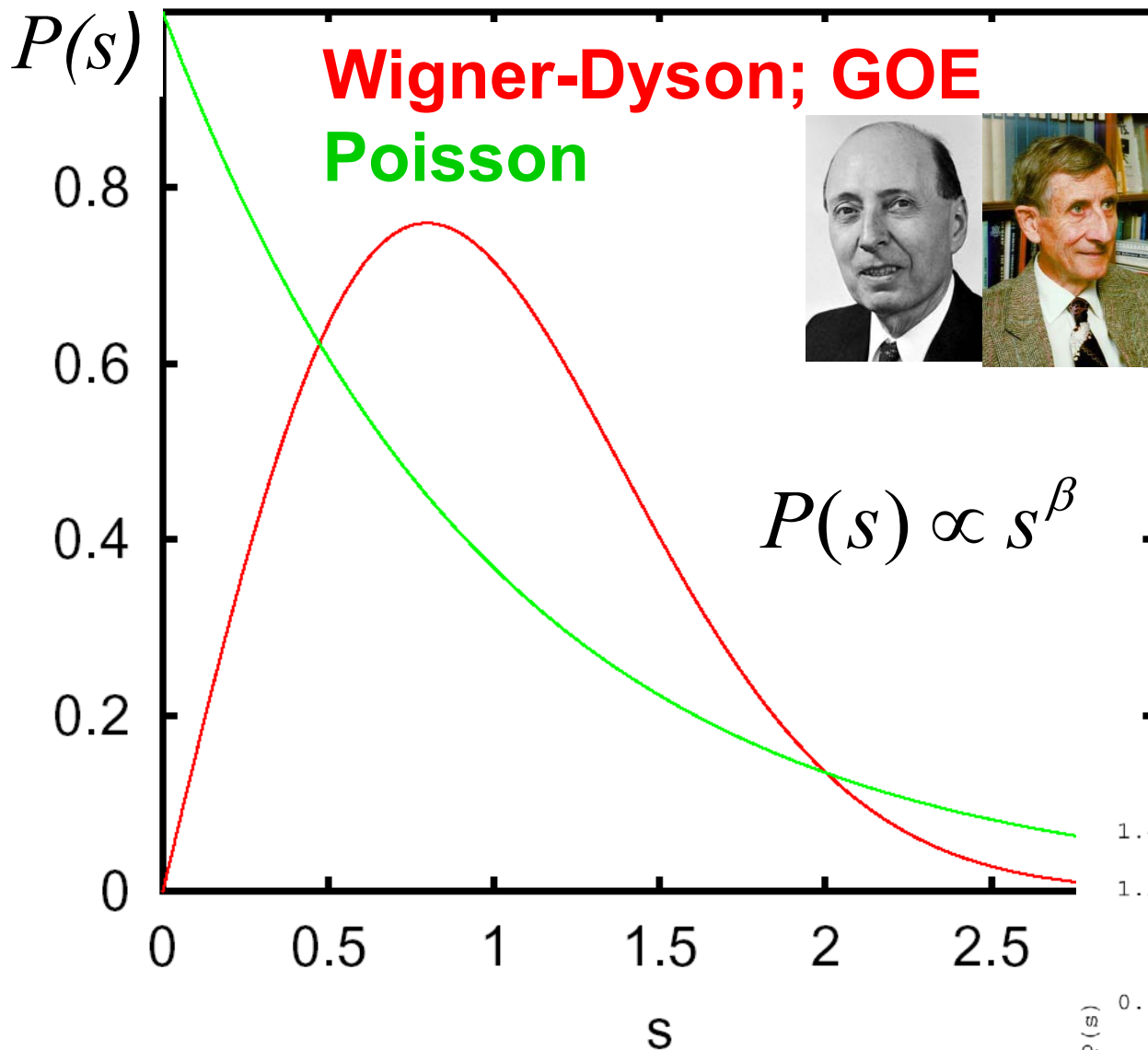
- distribution function of nearest
neighbors spacing between

Spectral Rigidity

$$P(s = 0) = 0$$

Level repulsion

$$P(s \ll 1) \propto s^\beta \quad \beta=1,2,4$$



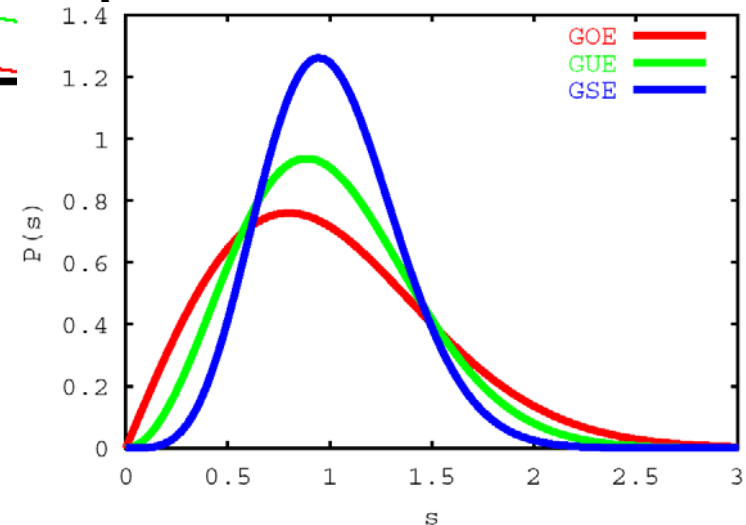
**Gaussian
Orthogonal
Ensemble**

Orthogonal
 $\beta=1$

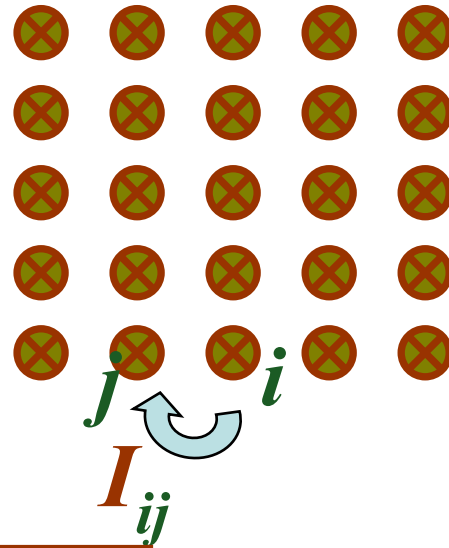
Unitary
 $\beta=2$

Symplectic
 $\beta=4$

Poisson – completely uncorrelated levels



Anderson Model



- *Lattice - tight binding model*
- *Onsite energies ϵ_i - **random***
- *Hopping matrix elements I_{ij}*

$$-W < \epsilon_i < W$$

uniformly distributed

Is there much in common between Random Matrices and Hamiltonians with random potential ?

Q • What are the spectral statistics of a finite size Anderson model ?

Anderson Transition

Strong disorder

$$I < I_c$$

Insulator

All eigenstates are localized
Localization length ξ

The eigenstates, which are localized at different places will not repel each other



Poisson spectral statistics

Weak disorder

$$I > I_c$$

Metal

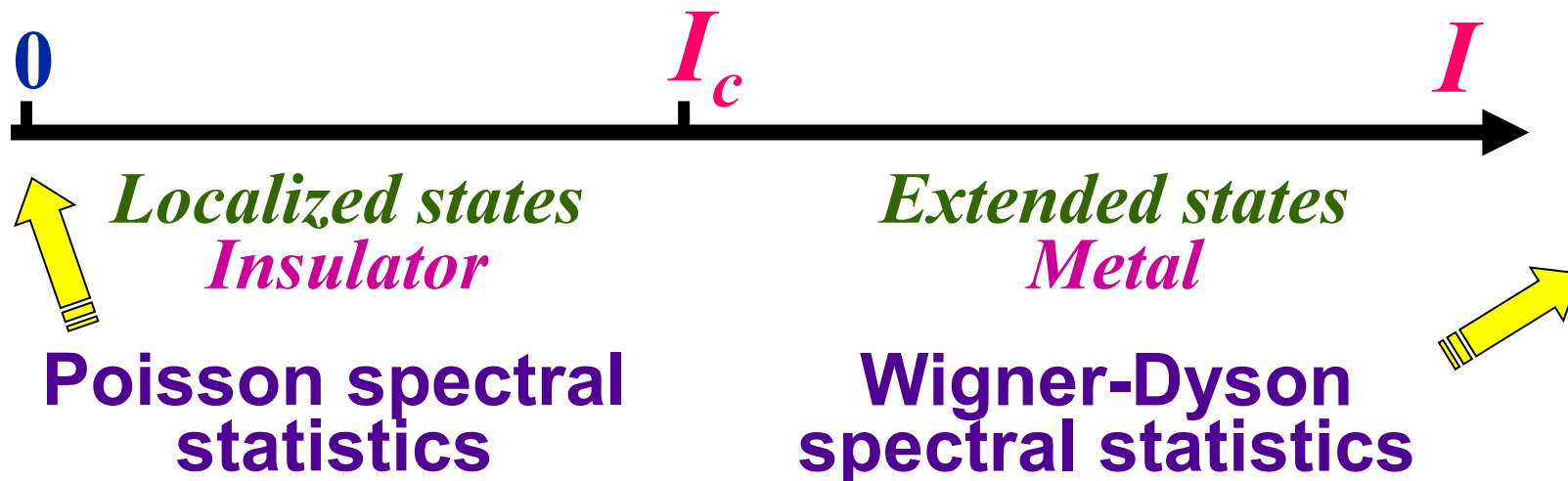
There appear states extended all over the whole system

Any two extended eigenstates repel each other



Wigner – Dyson spectral statistics

Anderson Localization and Spectral Statistics



Extended states: Level repulsion, anticrossings,
Wigner-Dyson spectral statistics

Localized states: **Poisson** spectral statistics

Invariant (basis independent) definition

In general:

Localization in the space of quantum numbers.

KAM tori \longleftrightarrow localized states.

Glossary

Classical	Quantum
Integrable $H_0 = H_0(\vec{I})$	Integrable $\hat{H}_0 = \sum_{\mu} E_{\mu} \mu\rangle\langle\mu , \quad \mu\rangle = \vec{I}\rangle$
KAM	Localized
Ergodic - distributed all over the energy shell Chaotic	Extended ?

Many-Body Localization

BA, Gefen, Kamenev & Levitov, 1997

Basko, Aleiner & BA, 2005. . .

Example: Random Ising model in the perpendicular field

Will not discuss today in detail

$$\hat{H} = \sum_{i=1}^N B_i \hat{\sigma}_i^z + \sum_{i \neq j} J_{ij} \hat{\sigma}_i^z \hat{\sigma}_j^z + I \sum_{i=1}^N \hat{\sigma}_i^x \equiv \hat{H}_0 + I \sum_{i=1}^N \hat{\sigma}_i^x$$

Random Ising model
in a parallel field

Perpendicular
field

$\vec{\sigma}_i$ - Pauli matrices, $\sigma_i^z = \pm \frac{1}{2}$
 $i = 1, 2, \dots, N; \quad N \gg 1$

Without perpendicular field all σ_i^z
commute with the Hamiltonian, i.e.
they are integrals of motion

$$\hat{H} = \sum_{i=1}^N B_i \hat{\sigma}_i^z + \sum_{i \neq j} J_{ij} \hat{\sigma}_i^z \hat{\sigma}_j^z + I \sum_{i=1}^N \hat{\sigma}_i^x \equiv \hat{H}_0 + I \sum_{i=1}^N \hat{\sigma}_i^x$$

Random Ising model
in a parallel field

Perpendicular
field

$\vec{\sigma}_i$ - Pauli matrices

$i = 1, 2, \dots, N; \quad N \gg 1$

Without perpendicular field
all σ_i^z commute with the
Hamiltonian, i.e. they are
integrals of motion

**Anderson Model on
N-dimensional cube**

$\{\sigma_i^z\}$ determines a site

$$H_0 \left(\{\sigma_i\} \right)$$

onsite energy

$$\hat{\sigma}^x = \hat{\sigma}^+ + \hat{\sigma}^-$$

hopping between
nearest neighbors

$$\hat{H} = \sum_{i=1}^N B_i \hat{\sigma}_i^z + \sum_{i \neq j} J_{ij} \hat{\sigma}_i^z \hat{\sigma}_j^z + I \sum_{i=1}^N \hat{\sigma}_i^x \equiv \hat{H}_0 + I \sum_{i=1}^N \hat{\sigma}_i^x$$

Anderson Model on N -dimensional cube

Usually:

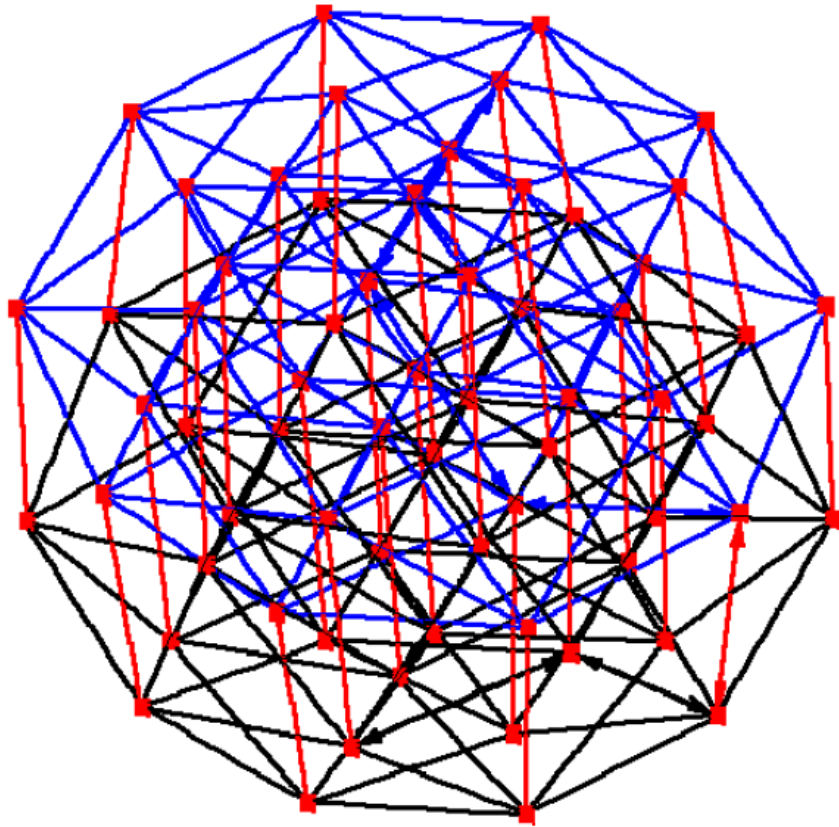
of dimensions $d \rightarrow \text{const}$

system linear size $L \rightarrow \infty$

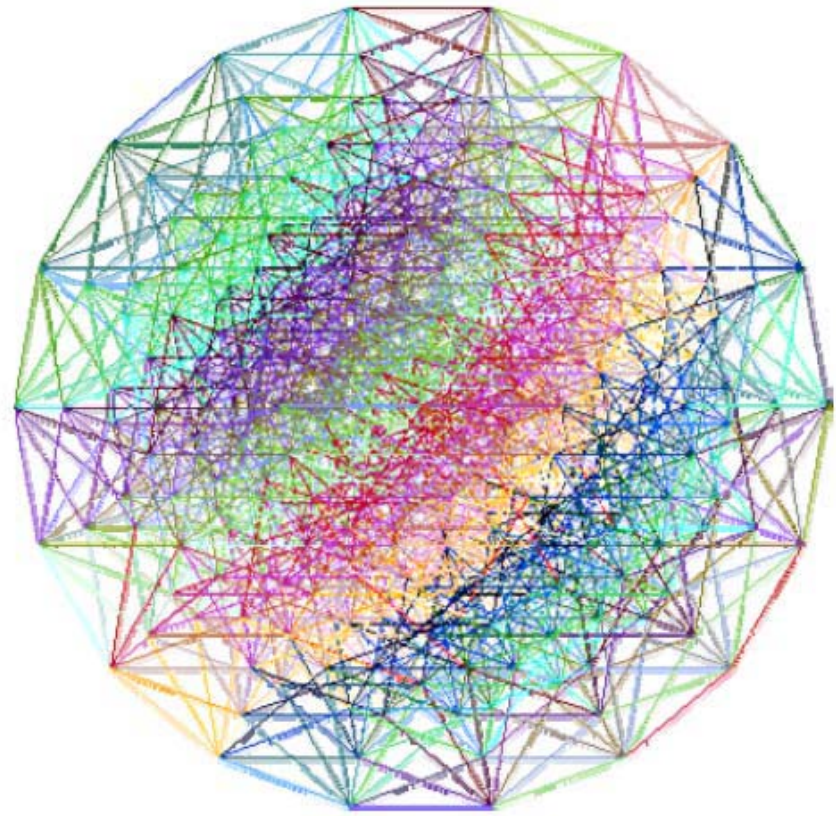
Here:

of dimensions $d = N \rightarrow \infty$

system linear size $L = 1$



6-dimensional cube



9-dimensional cube

$$\hat{H} = \sum_{i=1}^N B_i \hat{\sigma}_i^z + \sum_{i \neq j} J_{ij} \hat{\sigma}_i^z \hat{\sigma}_j^z + I \sum_{i=1}^N \hat{\sigma}_i^x \equiv \hat{H}_0 + I \sum_{i=1}^N \hat{\sigma}_i^x$$

Anderson Model on N -dimensional cube

- Localization:**
- No relaxation
 - No equipartition
 - No temperature
 - No thermodynamics

Glass ??